

MOSFETs Silicon N-Channel MOS

SSM3K72KCT

1. Applications

· High-Speed Switching

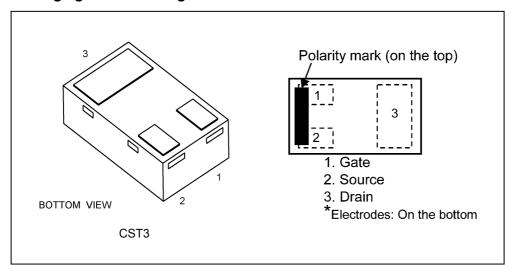
2. Features

- (1) ESD(HBM) level 2 kV
- (2) Low drain-source on-resistance
 - : $R_{DS(ON)} = 1.05 \Omega \text{ (typ.) } (@V_{GS} = 10 \text{ V})$

 $R_{\rm DS(ON)} = 1.15~\Omega~{\rm (typ.)}~(@V_{\rm GS} = 5.0~{\rm V})$

 $R_{\mathrm{DS(ON)}} = 1.2~\Omega~\mathrm{(typ.)}~(@V_{\mathrm{GS}} = 4.5~\mathrm{V})$

3. Packaging and Pin Assignment





4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics | | Symbol | Rating | Unit |
|------------------------|--------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 60 | V |
| Gate-source voltage | | V_{GSS} | ±20 | |
| Drain current (DC) | (Note 1) | I _D | 400 | mA |
| Drain current (pulsed) | (Note 1), (Note 2) | I _{DP} | 1200 | |
| Power dissipation | (Note 3) | P_{D} | 500 | mW |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature | | T _{stg} | -55 to 150 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150 °C.
- Note 2: pulse width \leq 10 μ s, Duty \leq 1 %
- Note 3: Device mounted on a 25.4 mm × 25.4 mm × 1.6 mm FR4 glass epoxy board (Cu pad: 645 mm²)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The channel-to-ambient thermal resistance, R_{th(ch-a)}, and the drain power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



5. Electrical Characteristics

5.1. Static Characteristics (Unless otherwise specified, $T_a = 25$ °C)

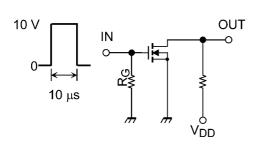
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------|----------------------|---------------------------------------------------|-----|------|------|------|
| Gate leakage current | | I _{GSS} | $V_{DS} = 0 \text{ V}, V_{GS} = \pm 16 \text{ V}$ | _ | | ±10 | μА |
| Drain cut-off current | | I _{DSS} | V _{DS} = 60 V, V _{GS} = 0 V | _ | | 1 | |
| Drain-source breakdown voltage | | V _{(BR)DSS} | $I_D = 250 \mu A, V_{GS} = 0 V$ | 60 | | | V |
| Gate threshold voltage | | V_{th} | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 1.1 | | 2.1 | |
| Drain-source on-resistance | (Note 1) | R _{DS(ON)} | I_D = 100 mA, V_{GS} = 4.5 V | _ | 1.2 | 1.75 | Ω |
| | | | I _D = 100 mA, V _{GS} = 5.0 V | _ | 1.15 | 1.65 | |
| | | | I _D = 100 mA, V _{GS} = 10 V | _ | 1.05 | 1.5 | |
| Forward transfer admittance | (Note 1) | Y _{fs} | V _{DS} = 10 V, I _D = 200 mA | _ | 1 | _ | S |

Note 1: Pulse measurement.

5.2. Dynamic Characteristics (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|---------------------|-----------------------------------------------------------------------------------------------------|-----|------|-----|------|
| Input capacitance | C _{iss} | $V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ | _ | 26 | 40 | pF |
| Reverse transfer capacitance | C _{rss} | f = 1 MHz | _ | 1.3 | | |
| Output capacitance | Coss | | _ | 5.5 | | |
| Switching time (rise time) | t _r | V_{DD} = 30 V, I_{D} = 200 mA, | _ | 3.6 | | ns |
| Switching time (turn-on delay time) | t _{d(on)} | V_{GS} = 0 to 10 V, R_{G} = 50 Ω Duty \leq 1%, V_{IN} : t_{r} , t_{f} < 5 ns, | _ | 5.5 | 11 | |
| Switching time (fall time) | t _f | Common source, | _ | 17 | _ | |
| Switching time (turn-off delay time) | t _{d(off)} | See Chapter 5.3. | _ | 38 | 90 | |

5.3. Switching Time Test Circuit



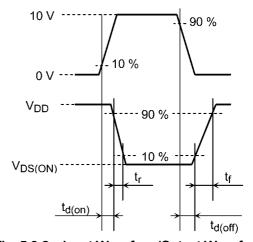


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform

5.4. Gate Charge Characteristics (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------------------------|-----------------|------------------------------------|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | V_{DD} = 30 V, I_{D} = 200 mA, | _ | 0.39 | 0.6 | nC |
| Gate-source charge | Q _{gs} | V _{GS} = 4.5 V | _ | 0.2 | | |
| Gate-drain charge | Q_{gd} | | _ | 0.11 | | |

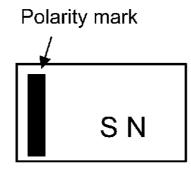


5.5. Source-Drain Characteristics (Unless otherwise specified, T_a = 25 °C)

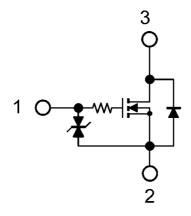
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------|---------|-----------|-----------------------------------------------|-----|-------|------|------|
| Diode forward voltage (| Note 1) | V_{DSF} | $I_D = -115 \text{ mA}, V_{GS} = 0 \text{ V}$ | _ | -0.79 | -1.1 | ٧ |

Note 1: Pulse measurement.

6. Marking



7. Equivalent Circuit



8. Characteristics Curves (Note)

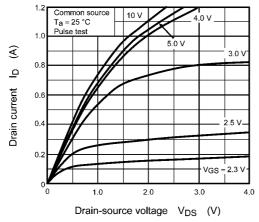


Fig. 8.1 I_D - V_{DS}

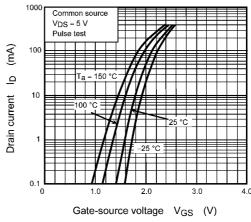


Fig. 8.2 I_D - V_{GS}

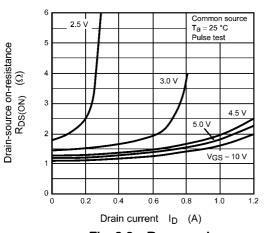


Fig. 8.3 R_{DS(ON)} - I_D

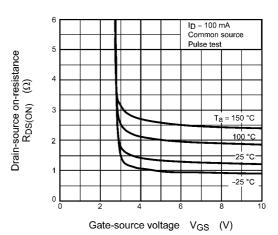


Fig. 8.4 R_{DS(ON)} - V_{GS}

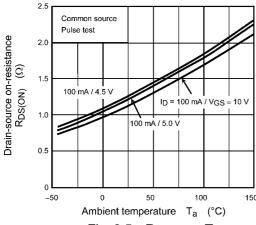


Fig. 8.5 R_{DS(ON)} - T_a

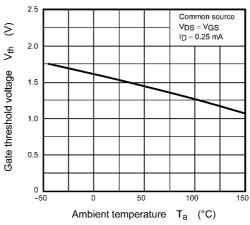
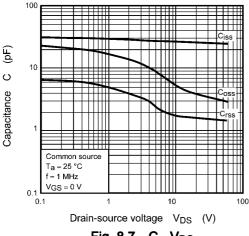
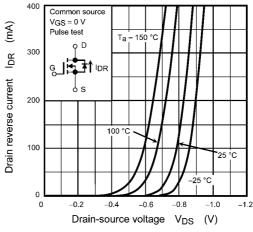
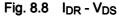


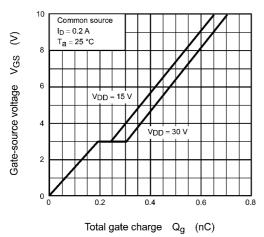
Fig. 8.6 V_{th} - T_a











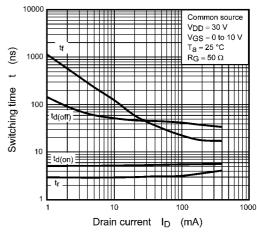
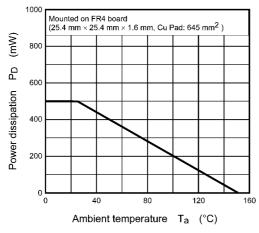


Fig. 8.9 Dynamic Input Characteristics

Fig. 8.10 t - I_D



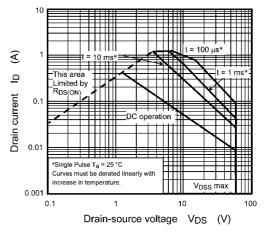


Fig. 8.11 P_D - T_a

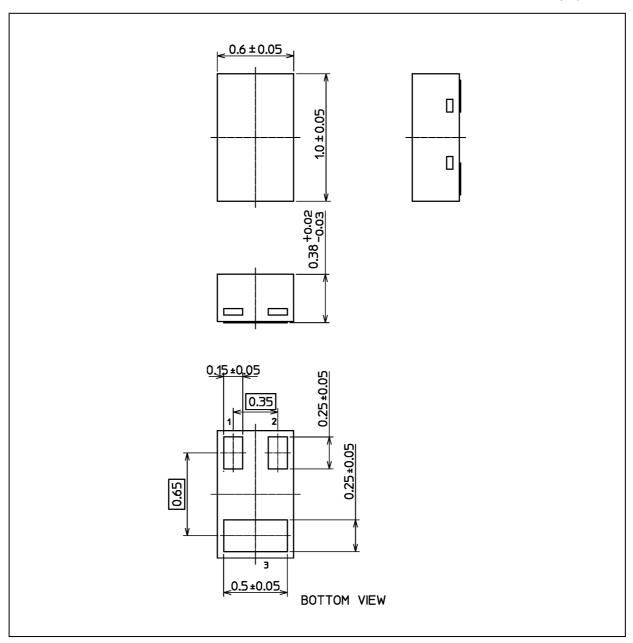
Fig. 8.12 Safe Operating Area

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.75 mg (typ.)

| Package Name(s) |
|-----------------|
| TOSHIBA: 1-1S1S |
| Nickname: CST3 |



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